

January 1995

# 74F2240

## Octal Buffer/Line Driver with 25Ω Series Resistors in the Outputs

### General Description

The 74F2240 is an inverting octal buffer and line driver designed to drive capacitive inputs of MOS memory devices, address and clock lines or act as a low undershoot general purpose bus driver.

The 25Ω series resistor in the outputs reduces undershoot and ringing and eliminates the need for external resistors.

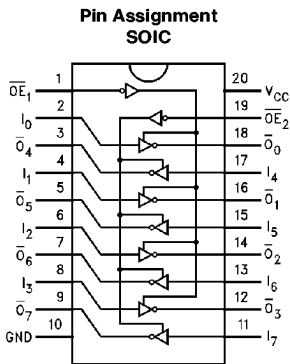
### Features

- TRI-STATE® outputs drive bus lines or buffer memory address registers
- Outputs sink 12 mA and source 15 mA
- 25Ω series resistors in outputs eliminate the need for external resistors
- Designed to drive the capacitive inputs of MOS devices
- Guaranteed 4000V minimum ESD protection

Commercial	Military	Package Number	Package Description
74F2240SC (Note 1)		M20B	20-Lead (0.300" Wide) Molded Small Outline, JEDEC
74F2240SJ (Note 1)		M20D	20-Lead (0.300" Wide) Molded Small Outline, EIAJ

Note 1: Devices also available in 13" reel. Use suffix = SCX and SJX.

### Connection Diagram



TL/F/10898-1

### Truth Table

OE <sub>1</sub>	D <sub>1n</sub>	O <sub>1n</sub>	OE <sub>2</sub>	D <sub>2n</sub>	O <sub>2n</sub>
H	X	Z	H	X	Z
L	H	L	L	H	L
L	L	H	L	L	H

### Unit Loading/Fan Out:

Pin Names	Description	74F	
		U.L. High/Low	Output I <sub>OH</sub> /I <sub>OL</sub>
OE <sub>1</sub> , OE <sub>2</sub>	TRI-STATE Output Enable Input (Active LOW)	1.0/1.667	20 μA/ - 1 mA
I <sub>0</sub> -I <sub>7</sub>	Inputs	1.0/1.667	20 μA/ - 1 mA
O <sub>0</sub> -O <sub>7</sub>	Outputs	750/20	- 15 mA/ 12 mA

TRI-STATE® is a registered trademark of National Semiconductor Corporation.

## Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +175°C
Plastic	−55°C to +150°C

V <sub>CC</sub> Pin Potential to Ground Pin	−0.5V to +7.0V
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Input Voltage (Note 2)	−0.5V to +7.0V
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Input Current (Note 2)	−30 mA to +5.0 mA
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Voltage Applied to Output in HIGH State (with V <sub>CC</sub> = 0V)	
Standard Output	−0.5V to V <sub>CC</sub>
TRI-STATE Output	−0.5V to +5.5V

Current Applied to Output in LOW State (Max)	twice the rated I <sub>OL</sub> (mA)
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ESD Last Passing Voltage (Min)	4000V
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**Note 1:** Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

**Note 2:** Either voltage limit or current limit is sufficient to protect inputs.

## Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Commercial	
Supply Voltage	4.5V to 5.5V
Commercial	

## DC Electrical Characteristics

Symbol	Parameter	74F			Units	V <sub>CC</sub>	Conditions
		Min	Typ	Max			
V <sub>IH</sub>	Input HIGH Voltage	2.0			V		Recognized as a HIGH Signal
V <sub>IL</sub>	Input LOW Voltage			0.8	V		Recognized as a LOW Signal
V <sub>CD</sub>	Input Clamp Diode Voltage			−1.2	V	Min	I <sub>IN</sub> = −18 mA
V <sub>OH</sub>	Output HIGH Voltage	74F 10% V <sub>CC</sub> 74F 10% V <sub>CC</sub>	2.4 2.0		V	Min	I <sub>OH</sub> = −3 mA I <sub>OH</sub> = −15 mA
V <sub>OL</sub>	Output LOW Voltage	74F 10% V <sub>CC</sub>		0.75	V	Min	I <sub>OL</sub> = 12 mA
I <sub>IH</sub>	Input HIGH Current	74F		5.0	μA	Max	V <sub>IN</sub> = 2.7V
I <sub>BVI</sub>	Input HIGH Current Breakdown Test	74F		7.0	μA	μA	V <sub>IN</sub> = 7.0V
I <sub>CEX</sub>	Output HIGH Leakage Current	74F		50	μA	Max	V <sub>OUT</sub> = V <sub>CC</sub>
V <sub>ID</sub>	Input Leakage Test	74F	4.75		V	0.0	I <sub>ID</sub> = 1.9 μA All Other Pins Grounded
I <sub>OD</sub>	Output Leakage Circuit Current	74F		3.75	μA	0.0	V <sub>IOD</sub> = 150 mV All Other Pins Grounded
I <sub>IL</sub>	Input LOW Current			−1.0	mA	Max	V <sub>IN</sub> = 0.5V (OE <sub>1</sub> , OE <sub>2</sub> , D <sub>n</sub> )
I <sub>OZH</sub>	Output Leakage Current			50	μA	Max	V <sub>OUT</sub> = 2.7V
I <sub>OZL</sub>	Output Leakage Current			−50	μA	Max	V <sub>OUT</sub> = 0.5V
I <sub>OS</sub>	Output Short-Circuit Current	−100		−225	mA	Max	V <sub>OUT</sub> = 0V
I <sub>ZZ</sub>	Bus Drainage Test			500	μA	0.0V	V <sub>OUT</sub> = 5.25V

## DC Electrical Characteristics (Continued)

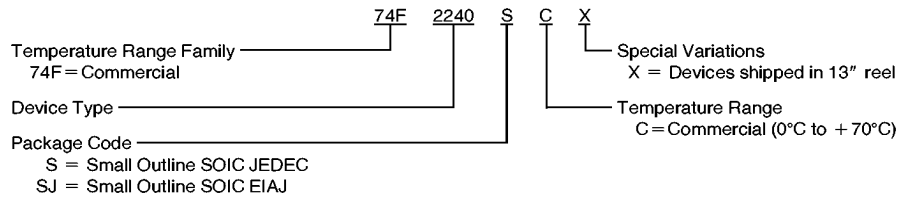
Symbol	Parameter	74F			Units	V <sub>CC</sub>	Conditions
		Min	Typ	Max			
I <sub>OCH</sub>	Power Supply Current		16	29	mA	Max	V <sub>O</sub> = HIGH
I <sub>OCL</sub>	Power Supply Current		47	75	mA	Max	V <sub>O</sub> = LOW
I <sub>CCZ</sub>	Power Supply Current		45	63	mA	Max	V <sub>O</sub> = HIGH Z

## AC Electrical Characteristics

Symbol	Parameter	74F			74F		Units
		$T_A = +25^{\circ}\text{C}$ $V_{CC} = +5.0\text{V}$ $C_L = 50\text{ pF}$			$T_A, V_{CC} = \text{Com}$ $C_L = 50\text{ pF}$		
		Min	Typ	Max	Min	Max	
t <sub>PLH</sub>	Propagation Delay	3.0	4.9	7.5	3.0	7.5	ns
t <sub>PHL</sub>	Data to Output	2.0	3.7	6.0	2.0	6.0	
t <sub>PZH</sub>	Output Enable Time	2.0	3.9	6.5	2.0	7.0	ns
t <sub>PZL</sub>		4.0	6.7	9.5	4.0	10.0	
t <sub>PHZ</sub>	Output Disable Time	2.0	4.1	6.5	2.0	7.0	ns
t <sub>PLZ</sub>		2.0	4.9	8.5	2.0	9.5	

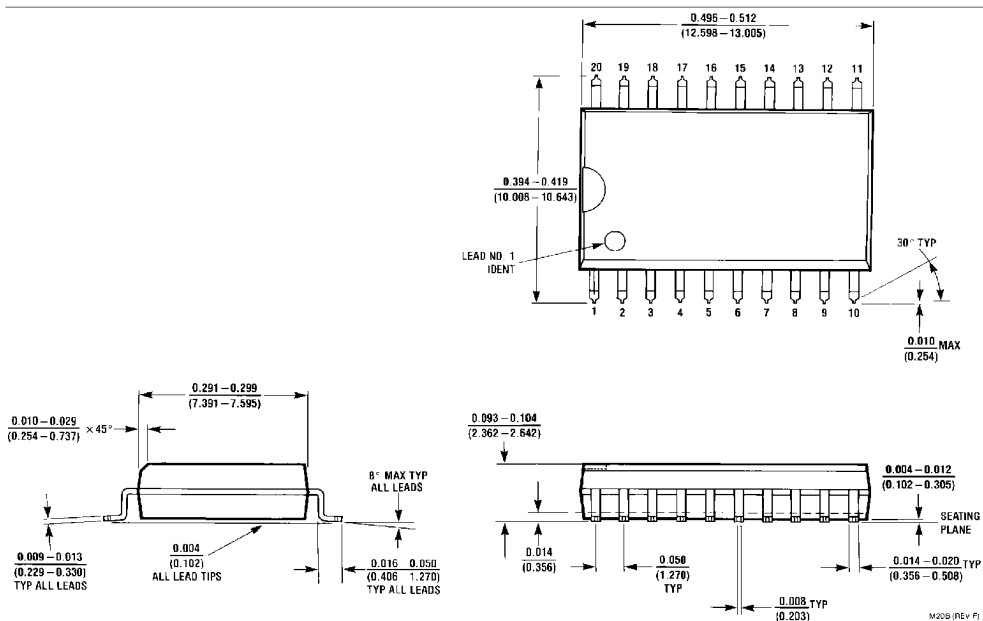
## Ordering Information

The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:



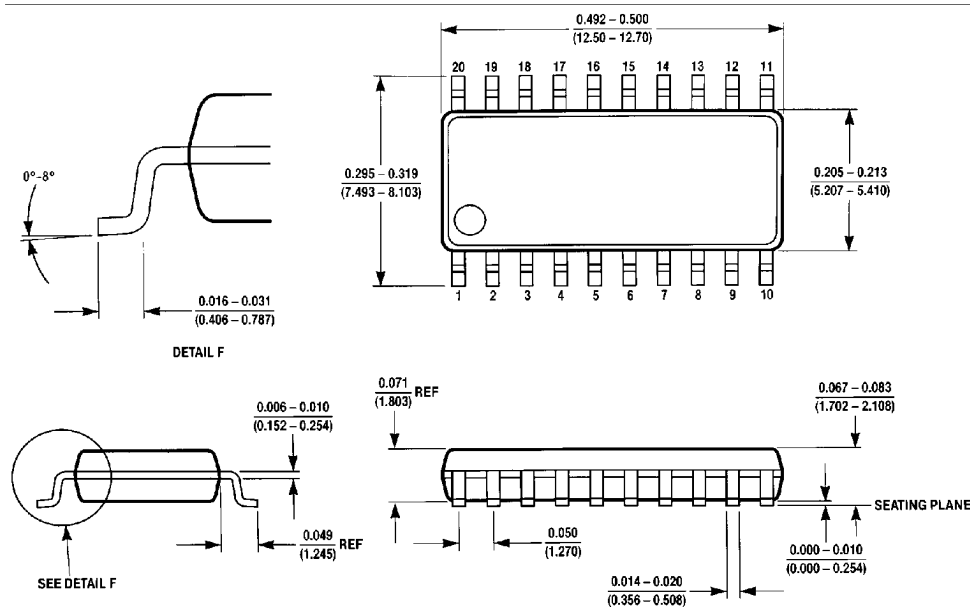
[查询"74F2240SJ"供应商](#)

### Physical Dimensions inches (millimeters)



**20-Lead (0.300" Wide) Molded Small Outline Package, JEDEC (S)  
NS Package Number M20B**

# Physical Dimensions inches (millimeters) (Continued)



20-Lead (0.300" Wide) Molded Small Outline Package, EIAJ  
NS Package Number M20D

M20D (REV A)

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